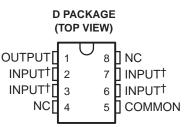
SLVS011D - OCTOBER 1982 - REVISED AUGUST 2003

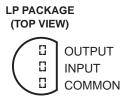
- 3-Terminal Regulators
- Output Current Up To 100 mA
- No External Components Required
- Internal Thermal-Overload Protection
- Internal Short-Circuit Current Limiting
- Direct Replacement for Industry-Standard MC79L00 Series
- Available in 5% or 10% Selections

description/ordering information

This series of fixed negative-voltage integrated-circuit voltage regulators is designed for a wide range of applications. These include on-card regulation for elimination of noise and distribution problems associated with single-point



[†] Internally connected NC – No internal connection



regulation. In addition, they can be used to control series pass elements to make high-current voltage-regulator circuits. One of these regulators can deliver up to 100 mA of output current. The internal current-limiting and thermal-shutdown features essentially make the regulators immune to overload. When used as a replacement for a Zener-diode and resistor combination, these devices can provide an effective improvement in output impedance of two orders of magnitude, with lower bias current.

Тј	OUTPUT VOLTAGE TOLERANCE	NOMINAL OUTPUT VOLTAGE (V)	PACKAG	Eţ	ORDERABLE PART NUMBER	TOP-SIDE MARKING
				Tube of 75	MC79L05ACD	701.054
		-	SOIC (D)	Reel of 2500	MC79L05ACDR	79L05A
		-5	TO 000 (TO 00 (I D)	Bulk of 1000	MC79L05ACLP	701.054.0
			TO-226 / TO-92 (LP)	Reel of 2000	MC79L05ACLPR	79L05AC
				Tube of 75	MC79L12ACD	701.404
	5%	40	SOIC (D)	Reel of 2500	MC79L12ACDR	79L12A
0°C to 125°C		-12		Bulk of 1000	MC79L12ACLP	701 40 40
			TO-226 / TO-92 (LP)	Reel of 2000	MC79L12ACLPR	79L12AC
				Bulk of 1000	MC79L15ACLP	
		-15	TO-226 / TO-92 (LP)	Ammo of 2000	MC79L15ACLPM	79L15AC
				Reel of 2000	MC79L15ACLPR	
	1.09/	-12	TO-226 / TO-92 (LP)	Bulk of 1000	MC79L12CLP	79L12C
	10%	-15	SOIC (D)	Tube of 75	MC79L15CD	79L15C

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



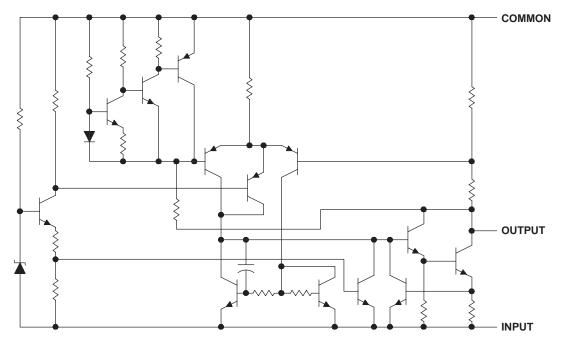
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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equivalent schematic



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Input voltage: MC79L05	30 V
MC79L12, MC79L15	
Package thermal impedance, θ_{JA} (see Notes 1 and 2): D package	
LP package	140°C/W
Operating free-air, case, or virtual junction temperature	150°C
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

			MIN	MAX	UNIT
		MC79L05	-7	-20	
V	Input voltage	MC79L12	-14.5	-27	V
		MC79L15	-17.5	-30	
IO	Output current			100	mA
ТJ	Operating virtual junction temperature		0	125	°C



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DADAMETER		T.	M	C79L05	С	MC	79L05A	C	
PARAMETER	TEST CONDITIONS [†]	Тј	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
		25°C	-4.6	-5	-5.4	-4.8	-5	-5.2	
Output voltage‡	$V_{I} = -7 V \text{ to } -20 V,$ I _O = 1 mA to 40 mA	0°C to 125°C	-4.5		-5.5	-4.75		-5.25	V
	$V_{I} = -10 V$, $I_{O} = 1 mA$ to 70 mA	0°C to 125°C	-4.5		-5.5	-4.75		-5.25	
1 1 1 2	$V_{I} = -7 V \text{ to } -20 V$	0500			200			150	
Input regulation	$V_{I} = -8 V \text{ to } -20 V$	25°C			150			100	mV
Ripple rejection	$V_{I} = -8 V$ to $-18 V$, f = 120 Hz	25°C	40	49		41	49		dB
	$I_{O} = 1 \text{ mA to } 100 \text{ mA}$	0500			60			60	
Output regulation	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	25°C			30			30	mV
Output noise voltage	f = 10 Hz to 100 kHz	25°C		40			40		μV
Dropout voltage	I _O = 40 mA	25°C		1.7			1.7		V
D :		25°C			6			6	
Bias current		125°C			5.5			5.5	mA
D : (1)	$V_{I} = -8 V \text{ to } -20 V$	000 / 40500			1.5			1.5	
Bias current change	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C			0.2			0.1	mA
	1								

electrical characteristics at specified virtual junction temperature, $V_I = -10 V$, $I_O = 40 mA$ (unless otherwise noted)

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.
 [‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = -19$ V, $I_O = 40$ mA (unless otherwise noted)

		-	M	C79L12	С	МС	79L12A	NC	
PARAMETER	TEST CONDITIONS [†]	Тј	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
		25°C	-11.1	-12	-12.9	-11.5	-12	-12.5	
Output voltage‡	$V_{I} = -14.5 V \text{ to } -27 V,$ I _O = 1 mA to 40 mA	0°C to 125°C	-10.8		-13.2	-11.4		-12.6	V
	$V_I = -19 V$, $I_O = 1 mA$ to 70 mA	0°C to 125°C	-10.8		-13.2	-11.4		-12.6	
	$V_{I} = -14.5 V \text{ to } -27 V$				250			250	
Input regulation	$V_{I} = -16 V \text{ to } -27 V$	25°C			200			200	mV
Ripple rejection	$V_{I} = -15$ V to -25 V, f = 120 Hz	25°C	36	42		37	42		dB
	I _O = 1 mA to 100 mA	0.500			100			100	
Output regulation	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	25°C			50			50	mV
Output noise voltage	f = 10 Hz to 100 kHz	25°C		80			80		μV
Dropout voltage	I _O = 40 mA	25°C		1.7			1.7		V
		25°C			6.5			6.5	
Bias current		125°C			6			6	mA
D'an anna dalaman	$V_{I} = -16 V \text{ to } -27 V$	000 1- 40500			1.5			1.5	
Sias current change	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C			0.2			0.1	mA

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

[‡]This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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electrical characteristics at specified virtual junction temperature, $V_I = -23 V$, $I_O = 40 mA$ (unless otherwise noted)

	TEAT ADVIDUTION OF	-	M	C79L15	С	MC			
PARAMETER	TEST CONDITIONS [†]	Тј	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
		25°C	-13.8	-15	-16.2	-14.4	-15	-15.6	
Output voltage‡	$V_{I} = -17.5 V \text{ to } -30 V,$ $I_{O} = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C	-13.5		-16.5	-14.25		-15.75	V
	$V_{I} = -23 V$, $I_{O} = 1 mA$ to 70 mA	0°C to 125°C	-13.5		-16.5	-14.25		-15.75	
1 1 1 1 1	$V_{I} = -17.5 V \text{ to } -30 V$	0500			300			300	
Input regulation	$V_{I} = -17.5 \text{ V to } -30 \text{ V}$	25°C			250			250	mV
Ripple rejection	V _I = -18.5 V to -28.5 V, f = 120 Hz	25°C	33	39		34	39		dB
	I _O = 1 mA to 100 mA	0500			150			150	
Output regulation	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	25°C			75			75	mV
Output noise voltage	f = 10 Hz to 100 kHz	25°C		90			90		μV
Dropout voltage	I _O = 40 mA	25°C		1.7			1.7		V
		25°C			6.5			6.5	
Bias current		125°C			6			6	mA
D'an anna talan	$V_{I} = -20 V \text{ to } -30 V$	000 1- 40500			1.5			1.5	
ias current change	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	0°C to 125°C			0.2			0.1	mA

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.
 [‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
MC79L05ACD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L05A	Samples
MC79L05ACDE4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L05A	Samples
MC79L05ACDG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L05A	Samples
MC79L05ACDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L05A	Samples
MC79L05ACDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L05A	Samples
MC79L05ACDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L05A	Samples
MC79L05ACLP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L05AC	Samples
MC79L05ACLPE3	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L05AC	Samples
MC79L05ACLPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L05AC	Samples
MC79L12ACD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L12A	Samples
MC79L12ACDE4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L12A	Samples
MC79L12ACDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 125	79L12A	Samples
MC79L12ACLP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L12AC	Samples
MC79L12ACLPE3	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L12AC	Samples
MC79L12ACLPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L12AC	Samples
MC79L12ACLPRE3	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L12AC	Samples
MC79L12CLP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L12C	Samples
MC79L15ACLP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L15AC	Samples
MC79L15ACLPE3	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L15AC	Samples
MC79L15ACLPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L15AC	Samples



13-Aug-2024

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
MC79L15ACLPRE3	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	0 to 125	79L15AC	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MC79L05ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
MC79L12ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

25-Sep-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MC79L05ACDR	SOIC	D	8	2500	353.0	353.0	32.0
MC79L12ACDR	SOIC	D	8	2500	353.0	353.0	32.0

TEXAS INSTRUMENTS

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25-Sep-2024

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
MC79L05ACD	D	SOIC	8	75	507	8	3940	4.32
MC79L05ACDE4	D	SOIC	8	75	507	8	3940	4.32
MC79L05ACDG4	D	SOIC	8	75	507	8	3940	4.32
MC79L12ACD	D	SOIC	8	75	507	8	3940	4.32
MC79L12ACDE4	D	SOIC	8	75	507	8	3940	4.32

D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



GENERIC PACKAGE VIEW

TO-92 - 5.34 mm max height TRANSISTOR OUTLINE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



LP0003A



PACKAGE OUTLINE

TO-92 - 5.34 mm max height

TO-92



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
 Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

 - a. Straight lead option available in bulk pack only.b. Formed lead option available in tape and reel or ammo pack.
 - c. Specific products can be offered in limited combinations of shipping medium and lead options.
 - d. Consult product folder for more information on available options.



LP0003A

EXAMPLE BOARD LAYOUT

TO-92 - 5.34 mm max height

TO-92



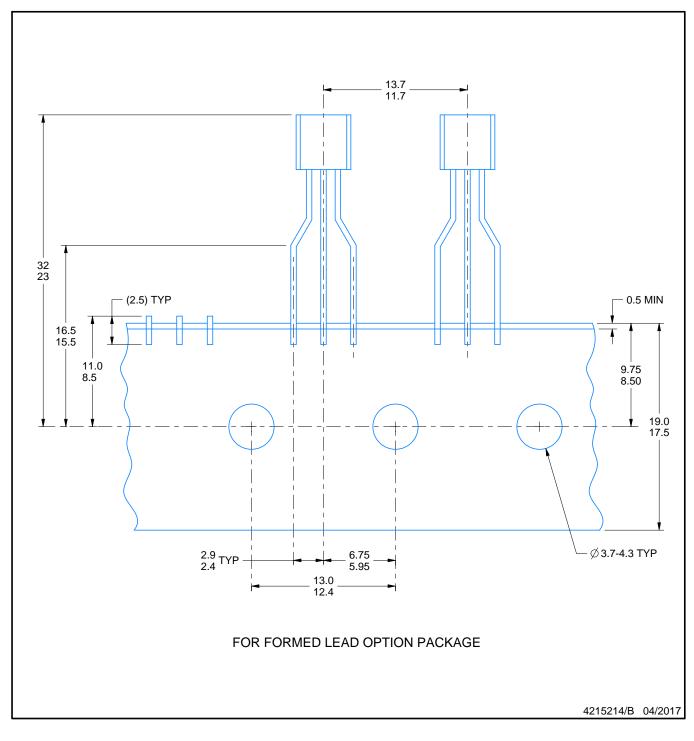


LP0003A

TAPE SPECIFICATIONS

TO-92 - 5.34 mm max height

TO-92





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